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High-rate in-plane micro-supercapacitors scribed onto photo paper using *in-situ* femtolaser-reduced graphene oxide/Au nanoparticle microelectrodes

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Direct laser-reduction of graphene oxide (GO), as a lithography-free approach, has been proven effective in manufacturing in-plane micro-supercapacitors (MSCs) with fast ion diffusion. However, the power density and charge/discharge rate are still limited by the relatively low conductivity of electrodes. Here, we report a facile approach by exploiting femtolaser insitu reduction of hydrated GO and chloroauric acid (HAuCl₄) nanocomposite simultaneously, which incorporates both the patterning of rGO electrodes and the fabrication of Au current collectors in a single step. These flexible MSCs boast achievements of one hundred fold increase in electrode conductivities up to 1.1×10⁶ S/m, which provide superior rate capability (50% for the charging rate increase from 0.1 V/s to 100 V/s), sufficiently high frequency responses (362 Hz, 2.76 ms time constant), and large specific capacitance of 0.77 mF/cm² (17.2 F/cm³ for volumetric capacitance) at 1 V/s, and 0.46 mF/cm² (10.2 F/cm³) at 100 V/s. The use of photo paper substrates enables the flexibility of this fabrication protocol. Moreover, proof-of-concept 3D MSCs are demonstrated with enhanced areal capacitance (up to 3.84 mF/cm² at 1 V/s) while keeping high rate capabilities. This prototype of all solid-state MSCs demonstrates the broad range of potentials of thin-film based energy storage device applications for flexible, portable, and wearable electronic devices that require a fast charge/discharge rate and high power density.

Introduction

Recent developments in portable electronics have shown an increased demand for miniaturized energy-storage units as flexible chips with enhanced functionality and integration capabilities. ¹⁻⁴ Notably, micro-supercapacitors (MSCs) are highly promising innovations for on-chip applications requiring a high spike of current as well as a high frequency response for alternating current (ac) line filtering. ^{3, 5-8} The capability of retaining high specific capacitance during ultrafast charging/discharging is essential for

these high-performance supercapacitor application. ⁹ Furthermore, the use of electric double-layer micro-supercapacitors (EDL-MSCs) is preferred due to their rapid and reversible adsorption/desorption of ions at the electrolyte–electrode interface. $^{10,\,11}$ In this regard, the EDL-MSCs require highly conducting electrodes with large accessible surface areas, and reduced graphene oxide (rGO) is regarded as a potentially excellent material for these EDL-MSC electrodes. $^{2,\,4,\,12,\,13}$

Planar rGO-MSCs significantly facilitate rapid ion transportation due to shorter ion diffusion pathways in comparison with those of conventional stacked supercapacitors. In these EDL rGO-MSCs, Au or Pt current collectors are used to further minimize internal resistance. However, the photolithography technology patterning of these rGO electrodes and wet etching process of Au/Pt current collectors I limit the potential to integrate them into flexible substrates such as heat sensitive polymers and papers.

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[†] Electronic Supplementary Information (ESI) available: XRD and high resolution XPS, bending performances, cycle life, five supplementary notes on calculation of the specific capacitance, comparison mechanism of FS and CW lasers, FS enhanced reduction of rGO/Au nanocomposites, mechanical flexibility of rGO/Au FS MSCs, and electrochemistry performance of rGO/Au MSCs with different concentrations of HAuCl₄, respectively. See DOI: 10.1039/x0xx000000x

Gao et al. described the direct writing of planar rGO MSCs through laser reduction and patterning hydrated GO films. Although the device suffered from a low charge/discharge rate due to its high internal resistance, laser writing technology is a flexible and simplified method for MSC fabrication. El-Kady et al, 15 later reported laser scribed rGO-MSCs using a LightScribe DVD optical drive, and demonstrated that the restacking and agglomeration of graphene sheets are suppressed through laser reduction. Furthermore, the laser-written interdigitated MSCs displayed enhanced charge-storage capacity.³ These pioneering works paved a way toward the massive production of rGO-MSCs. Nevertheless, mainly due to the absence of highly conductive current collectors and as well as to the relatively low conductivity of laser script graphene (LSG) electrodes, the rate capability and time constant for laser-script MSCs is still limited compared with those of the MSCs fabricated by the conventional photolithography technique 4, 7. Thus, more innovative laser direct writing protocols are needed to develop highly conductive electrodes and current collectors for laser-scripted MSCs.

From a substrate perspective, cellulose-based paper holds great promise as a biodegradable substrate for flexible electronics because of its lowcost, disposability, flexibility, and ultra-thinness and lightness, ^{16, 17} with vast applications to antennas, ¹⁸ sensors, ¹⁹⁻²³ microfluidics, ²⁴ transistors, ²⁵⁻²⁷ solar cells, ^{28, 29} memory devices ³⁰ and batteries ³¹⁻³⁴. These devices reveal a trend towards incorporating different sensors and electronic components onto a single paper substrate to produce high-density integrated systems, ¹⁹ coupled with paper based supercapacitors. Nevertheless, other than a couple of examples ^{23, 35, 36} in a stacked structure, no study has focused on high rate in-plane MSCs on papers targeting the aforementioned applications, which also potentially substitutes conventional aluminum capacitors for paper electronics.

Herein, we report a facile approach by exploiting laser in-situ reduction of hydrated GO and chloroauric acid (HAuCl₄) nanocomposite simultaneously, which incorporates both the patterning of rGO electrodes and the fabrication of Au current collectors in a single step. The main objective of this innovative fabrication of EDL-MSCs is to develop highly conductive electrodes that allow high rate capability and fast frequency response. Also, prove of concept 3D MSCs are demonstrated with multifold increase of areal capacitance to fully utilize the limited space available for on chip energy storage. Unlike the continuous wave (CW) lasers, the use of femtosecond (FS) lasers provide excellent device performance by utilizing multiphoton polymerization, 37, 38 reduction, $^{39\text{-}41}$ melting $^{42,\,43}$ and etching. 43 The strong peak power of ultrashort pulses enables a nonlinear multiphoton interaction with the materials within the focal point, and leads to the following advantages: 1) high conductivity of rGO, 44 improving rate capability, 2) porous structures of rGO with enhanced accessible surface area, 12, 45, 46 increasing specific capacitance and 3) minimization of linewidth to a few micrometer or even sub-micrometer scale, facilitating the integration with on-chip devices. 47-49 Finally, the fabrication of MSCs on paper enables all paper-based systems that can work independently and sustainably. 50 Thereby, an additional merit of the present femtolaser-written EDL-MSCs is the ability to use cellulose-based paper substrates that are biodegradable and compatible with flexible electronics.

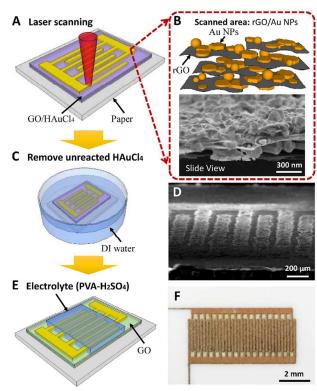


Fig. 1 Schematic illustration and photos of rGO/Au-MSCs (Microsupercapacitors) fabrication onto a paper substrate. The fabrication process includes: A) direct FS laser writing of rGO/Au microelectrodes, B) the SEM image of rGO/Au microelectrodes, C) removal of unreacted HAuCl₄ by rinsing in DI water, D) SEM image of the interdigitated rGO/Au microelectrodes, E) spreading PVA/H₂SO₄ electrolyte onto the microelectrodes, and F) the optical image of the final rGO/Au FS-MSC.

Experimental sections

All reagents used in the experiments were purchased from Fisher Scientific and used without further purification. The photo paper was purchased from Home Depot®.

Fabrication of MSCs on Paper

The fabrication process is conclude in Fig. 1 including following steps: applying GO/HAuCl₄ mixture onto photo paper, direct laser writing of rGO/Au electrodes, removal of unreacted HAuCl₄ and applying solid state electrolyte.

Aqueous dispersion of GO was fabricated from natural graphite flakes using a modified Hummers method, the details of which are described elsewhere. 51 The GO/HAuCl $_4$ mixture was prepared by dissolving 0.375 milli-molar gold chloride (HAuCl $_4$) into a 1 mL GO suspension at a GO concentration of 7.5 mg mL $^{-1}$. Then, the GO/HAuCl $_4$ mixture was spread onto a photo paper with an area density of 50 μ L cm $^{-2}$ and left at room temperature for several hours to dry.

Direct laser writing was conducted by a femtosecond fiber laser (Model: Cazadero, Calmar Laser Inc.) with 1030 nm central

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wavelength, and 400 fs pulse duration at a repetition rate of 120 kHz. Also, a CW laser (Verdi G5, Coherent) with 532 nm wavelength was used for laser writing to perform a comparative study. The laser beam was introduced into an upright microscope system and focused with a long working-distance 20x objective lens (LMPlan, NA0.40, Amscope). A computer-controlled 2-axis motorized platform moved the MSC samples at a typical writing speed of 1 mm s $^{\text{-}1}$ with a typical 80 mW laser power. The MSC contains interdigitated electrodes of approximately 140 μm in width with 60 μm spacing, conforming to a single cell dimension of 6.9 mm in length and 1.9 mm in width. The area of a single cell is thus 0.1311 cm 2 .

Laser written samples were rinsed with deionized water several times to remove unreacted HAuCl₄ and left to dry at room temperature. A similar process was used to prepare rGO microelectrodes from GO aqueous dispersion (7.5 mg mL⁻¹) without HAuCl₄.

The H_2SO_4/PVA hydrogel electrolyte was prepared following the procedure as previously reported.⁴ A thin layer of H_2SO_4/PVA hydrogel electrolyte was drop-casted onto the laser-written microelectrodes (10 μ L cm⁻²), which were left at room temperature overnight to ensure that the electrolyte completely diffused into the microelectrodes.

Characterization

The morphology and microstructures were characterized by a dual beam FIB/SEM instrument (Zeiss Auriga). Also, TEM and HRTEM observations were performed using a ZEISS LIBRA 200. Raman spectra were measured by a micro-Raman spectrometer using a laser excitation at 532 nm (Planar RAM-S Micro Raman System, Planartech, LLC). XPS analysis was performed using a PHI 5000 Versa Probe spectrometer (ULVAC-PHI, Japan) equipped with a monochromatic Al-Ka (1486.6 eV). X-ray source and an analyzer pass energy of 280 eV (55 eV for High-resolution XPS spectra). The electrode conductivities were determined from $\sigma = l/(\hbar vR)$, $^{52, 53}$ where the resistance R was measured by a digital voltmeter (HP 3456A), and $t,\ w$ and l are the electrode thickness, width, and length, respectively.

The electrochemical performances of the MSCs were examined by conducting a CV test, GCD test and EIS test using an electrochemical workstation (SP-200, Bio-Logic Science Instruments). Both CV and GCD tests were conducted using a two-electrode setup, while the EIS test was conducted over a frequency range from 0.1 Hz to 1 MHz with an amplitude of 10 mV at the open-circuit potential. Calculations of the specific capacitance are discussed in detail in Supplementary Note 1 (ESI).

Results and discussion

Femtolaser beam irradiation onto a gel layer of HAuCl₄ with GO sheets on a glossy photo paper substrate reduces HAuCl₄ to Au nanoparticles (NPs) and GO to rGO (Fig. 1A). Detailed XRD and XPS

spectra also confirmed the conversion of GO into rGO (Fig. S1, ESI). This FS laser writing creates a stacked-structure, with Au NPs of an average size of 150 nm attached to both sides of the rGO flakes, which are on the order of a few microns (Fig. 1B). These Au NPs act as nano-spacers between rGO sheets to constitute the rGO/Au microelectrode. More importantly, these Au NPs serve as highly conducting pathways⁵⁴ after sintering and significantly reduce the resistance of EDL-MSC electrodes. The constructed rGO/Au microelectrodes are immersed in deionized (DI) water to remove unreduced HAuCl₄ (Fig. 1C and 1D). Finally, the microelectrodes are coated with a thin layer of sulfuric acid/polyvinyl alcohol (H₂SO₄/PVA) hydrogel in order to conform to a solid state EDL-MSC (Fig. 1E and 1F).

Laser-written rGO/Au Electrodes

The detailed investigations of laser scripted rGO/Au electrodes as a function of laser power are shown in Fig. 2. The brighter SEM image intensity of the laser scanned area in Fig. 2A is attributed to the reduced Au NPs that emit abundant secondary electrons. Further magnified images show detailed definitions of Au NPs for the case of femtolaser at 1030 nm with a pulse duration of 400 fs (Fig. 2B) and for the case of comparative continue wave laser scanning at 532 nm (Fig. 2C). The gel layer of GO/HAuCl₄ is being reduced to rGO/Au (50 mW average laser power), the increase in laser power leads to the growth and sintering of Au NPs (80 mW), and further increased laser power transforms Au NPs into congregated Au spheres (200 mW).

Given the identical average laser power of 80 mW (as the red dash line marked in Fig. 2.), the prevailing photothermal effects of the CW laser generates sufficient heat energy to melt Au NPs, thus forming relatively discrete Au NPs, whereas the less prevailing photothermal energy of the FS laser forms continuous Au NPs membrane due to the multi-photon absorption mechanism (see Supplementary Note 2, ESI). The reduction mechanism of an FS laser is elucidated in two stages; multi-photon reduction prevails under the laser power slightly above the threshold (44 mW in this work), whereas photothermal reduction, sintering and melting dominate at a higher laser power.

Although laser reduction of GO has been extensively investigated, 10,15,44 the reduction of the Au nanoparticles can also be accomplished through various other reactions. Note that in our experiment no additional reducing agent was added. Instead, the three mechanisms were considered for the formation of ${\rm AuO}^{1}$: the reduction of ${\rm AuCl_4}^{-1}$ by either GO sheets 55 or laser reduced rGO sheets 56 as well as the thermal decomposition of ${\rm HAuCl_4}^{.57}$

Firstly, the AuCl₄ can be directly reduced by GO sheets, which are characterized by many small aromatic conjugated domains modified with the oxygen-containing functional groups, such as, carboxylic acid, hydroxyl, and epoxide groups. These aromatic conjugated domains act as electron-donating sources to reduce Au³⁺ and form Au NPs (reaction (R1)):⁵⁵

$$AuCl_4^- + 3e \rightarrow Au^0 \downarrow + 4Cl^- \tag{R1}$$

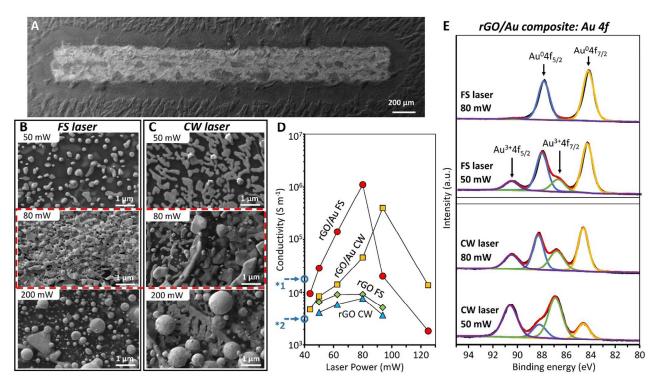


Fig. 2 Laser-written electrodes: A) SEM image of FS (femtosecond) laser-written rGO/Au microelectrodes, B) SEM images of the FS laser (1030 nm, 400 fs pulse duration)-written rGO/Au microelectrodes with average laser power of 50 mW, 80mW and 200 mW, c) SEM images of the FS laser (532 nm)-written rGO/Au microelectrodes with average laser power of 50 mW, 80mW, and 200 mW, D) conductivity of both the rGO/Au microelectrodes and rGO microelectrodes (markings *1 and *2 denote the reported conductivities for FS laser-reduced rGO^[23] and infrared CW laser-reduced rGO^[15], respectively), and E) XPS-fitted Au 4f core peaks for both the FS- and CW- rGO/Au microelectrodes.

This reaction is confirmed by an SEM image (Fig. S2A, ESI) displaying a few tiny Au NPs (less than 20 nm) formed on GO sheets and also by the XRD pattern (Fig. S2B, ESI) through simply adding $HAuCl_4 \cdot 4H_2O$ to a GO aqueous solution. Obviously, this mechanism does not account for large Au nanoparticles (a few hundred nanometers to micrometers) formed in the irradiated regions, as shown in Fig. 2B and Fig. 2C.

The second reductive mechanism likely involves Galvanic displacement^{58, 59} and redox reaction by relative potential difference. ^{56,60} It has been shown that when AuCl₃ (HAuCl₄·4H₂O, i.e. AuCl₃·HCl·4H₂O) is dissolved in a solvent, different ionic conformations can be formed depending on the type of coordinating agents. 61 Water (in this study) or acetonitrile preferentially leads to a square planar geometry of AuCl₄. 61 The reduction potential of the rGO (+0.38 V vs. SHE, standard hydrogen electrode) is much lower as compared to that of water-coordinated AuCl₄ (+1.002 V vs. SHE). 60,62 Therefore, gold cations (Au³⁺) can be reduced by electrons donated from negative-charged rGO sheets. 60 This reaction is the same as R1. in which the direct reduction from Au³+ to Au⁰ takes place.⁶³ It is important to point out that this mechanism only leads to nanoparticles formed in low density. Therefore, it should not account for the formation of the large amounts of Au nanoparticles shown in Fig. 2.

Lastly, the laser irradiation creates a strong photothermal effect which not only leads to the decomposition of AuCl₄⁻ through R2-R4,

 $^{\rm 57}$ but which also promotes aforementioned reaction through the reduction of GO:

$$HAuCl_4 \rightarrow HCl + AuCl_3$$
 (R2)

$$AuCl_3 \rightarrow Au + AuCl + Cl_2 (> 160 °C)$$
 (R3)

$$AuCl \rightarrow Au + Cl_2 (> 289 \, ^{\circ}C)$$
 (R4)

This process should be the main procedure to convert AuCl₄ to Au NPs for both lasers.

The rGO/Au microelectrodes show dramatically enhanced inplane conductivities up to two order-of-magnitudes larger than the rGO electrodes or as high as 1.1×10^6 S m⁻¹, which depicts the pronounced contributions of Au NPs to the enhancement of conductivity (Fig. 2D). The synergic effect of highly conductive Au NP membranes and bridge-connected rGO sheets with sintered Au NPs significantly increases the microelectrode conductivities. This highly conductive rGO/Au microelectrode reduces the internal resistance of EDL-MSC and promotes its charge/discharge rate capabilities. In contrast, a very low conductivity of 7.7×10^{-3} S m⁻¹ is measured for the non-scanned area of GO that serves as a separator, which is consistent with that of the previously reported hydrated GO.¹⁰

The conductivity of rGO/Au microelectrode increases with increasing laser power until it reaches a peak value and quickly decreases thereafter, as the bridge-connections of rGO sheets are weakened by laser ablation that separately distributes Au NPs (Fig. 2B and 2C) and breaks the conductive pathways. The substantially higher peak power of the pulsed FS laser is more aggressively

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damaging to the rGO/Au microelectrodes than the CW laser. This explains the reason for the maximum conductivity peak occurring at a lower laser power for the FS laser than CW laser (Fig. 2D). Also, SEM imaging clearly identifies the damaged area of the rGO/Au FS microelectrode (Fig. S3, ESI).

Additionally, the higher conductivity of rGO/Au FS in comparison to that of rGO/Au CW is mainly due to the enhanced reduction of gold from HAuCl₄ by FS laser writing as the X-ray photoelectron spectra (XPS) show in Fig. 2F. Both Au⁰4f^{5/2} (88.3 eV) and Au⁰4f^{7/2} (84.2 eV) peaks represent the binding energies of reduced Au NPs, whereas the minor peaks at higher binding energy (90.5 eV and 86.8 eV, respectively), represent Au ions adsorbed on the composite surface. 64, 65 The Au doublet peak intensities increase with increasing laser power. Furthermore, the FS laser more efficiently reduces HAuCl₄ to Au NPs showing much lower Au ion peaks in comparison with the CW laser. Meanwhile, femotolaserenhanced reduction of GO sheets with a higher C/O ratio of 12.57 in rGO/Au FS microelectrodes may also contribute to the higher conductivity of rGO-Au microelectrodes (Supplementary Note 3, ESI). Another factor, as aforementioned, that the more continues Au NPs membrane written by FS laser at a laser power of 80 mW provides more highly conductive pathways, which may response for the higher conductivity peak value of rGO/Au FS microelectrodes as

Note that, the FS laser scanning creates abundant nano-porous holes that increase the accessible surface areas and EDL-MSC capacitance (Fig. 3A and 3B). This is consistent with Raman spectra shown in Fig. 3C for the case of 80 mW laser power scanning. The reduction of GO sheets into rGO increases the Raman peak ratio of $\rm I_D/I_G$ from 0.91 to 0.94 (CW) or 1.03 (FS), which shows that FS laser reduction results in more structural changes and defects associated with increased nanoporous edges than CW laser reduction. This observation is conserved when Au NPs are reduced from HAuCl₄, showing an $\rm I_D/I_G$ increase to 0.90 and 1.09 for CW and FS lasers, respectively.

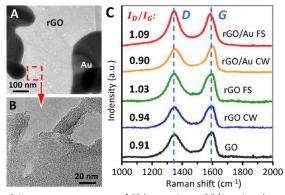


Fig. 3 Nano-porous structures of FS laser-written rGO/Au microelectrodes at a laser power of 80 mW: A) TEM and B) HRTEM images of the FS laser-written rGO/Au microelectrodes, showing the nano-porous structures, and C) Raman spectra of GO sheet (black curve), rGO microelectrodes (blue for CW and green for FS), and rGO/Au microelectrodes (orange for CW and red for FS).

Electrochemical Characterization of Laser-Written MSCs

To improve the charge/discharge rate capabilities of MSCs, a low equivalent series resistance (ESR) is required. Considering the morphological and electrical characteristics of FS laser written rGO/Au microelectrodes, therefore, the laser power of 80 mW was employed to provide the highest conductivity of microelectrodes to minimize ESR. 66

Cyclic voltammetry (CV) experiments (Fig. 4A and 4B) for the electrochemical performance evaluation of laser-written MSCs show that the rGO/Au FS-MSCs provide a fast charge transfer with a sufficiently low ESR, which is evidenced by retaining a quasi-rectangular CV curve for up to the scan rate of 100 V s $^{-1}$. 4 . 67 In the absence of Au NPs, despite of the quasi-rectangular shaped CV curves are observed at a scan rate of 1 V s $^{-1}$, the area of rGO-FS CV curve, which implies specific capacitance, diminishes to zero because of the enlarged ESR without any bridge-connections of rGO sheets by Au NPs; and thus, the CV curve collapses into a line at 100 V s $^{-1}$. Meanwhile, the narrower CV curves for the CW laser-written MSCs are mainly due to their relatively larger ESRs. This discrepancy is more pronounced with an increasing scan rate. 12

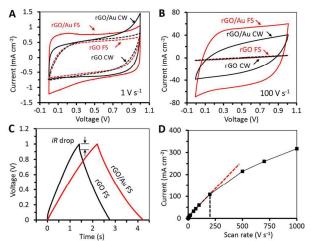


Fig. 4 Comparison of electrochemical performances of both the laser-written rGO/Au-MSCs and rGO-MSCs: A,B) cyclic voltammetry (CV) curves obtained at a scan rate of 1 V s^{-1} and 100 V s^{-1} , respectively, C) galvanostatic charge/discharge (GCD) curves measured at a scan rate of 50 μA (381 μA cm⁻²) for rGO/Au FS-MSCs and rGO FS-MSCs, D) the discharge current of rGO/Au FS-MSCs as a function of the scan rate.

The galvanostatic charge/discharge (GCD) curves for rGO/Au FS (Fig. 4C) show nearly symmetrical triangle-shaped curves as an ideal EDL-MSC with no apparent internal resistance (iR) drop. The slight non-linearity in the curves implies a charge–transfer phenomena that can be ascribed to the reaction of oxygen contained in the surface functional groups of rGO sheets. For rGO FS without Au NPs, however, the curves show a notable iR drop of about 0.1 V, which confirms a relatively larger ESR. For rGO/Au FS, the linear dependence of the discharge current density for the scan rate up to 200 V s⁻¹ (Fig. 4D) further demonstrates that the use of Au NPs significantly enhances the power output capabilities of MSCs.

As the current collector, the Au NPs contribute to remarkably enhancing the areal capacitance at high scan rates for rGO/Au FS-

MSCs as well as rGO/Au CW-MSCs (Fig. 5A) due to the reducing of ESR, while the EDL capacitance contributed by bare in-plane Au microelectrodes is very low (typically <0.01 mF cm 2 at a scan rate of 1 V s $^{-1}$ and <0.001 mF cm $^{-2}$ at a scan rate of 100 V s $^{-1}$). Therefore, the EDL capacitance of rGO/Au MSCs mainly comes from the ion absorption and desorption on rGO sheets surface, which is also evidenced by the areal capacitance close to 2 mF cm $^{-1}$ at a low scan rate of 0.1 V s $^{-1}$. Meanwhile, the nanoporous structures introduced by FS laser may contribute to enhance the specific capacitance of the FS laser-written MSCs at all scan rates due to the enlarged accessible area of rGO sheets.

The areal capacitance at 1 V s⁻¹ of rGO/Au FS-MSCs is superior to the other three tested MSCs (the inset graph in Fig. 5A); however, this superiority is dramatically more pronounced at a higher scan rate. At 100 V s⁻¹, for example, the areal capacitances of both rGO/Au FS-MSCs (0.46 mF cm⁻²) and rGO/Au CW-MSCs (0.20 mF cm⁻²) are over 100 times larger than those of the rGO based MSCs without Au NPs. At 1000 V s⁻¹, at which a smaller drop of areal capacitance is crucial to ensure the rate capability, the rGO/Au FS-MSCs provide a high areal capacitance of 95 μ F cm⁻², which is about 20 times higher than the previously reported areal capacitance for MSCs when using a plasma-reduced graphene oxide (4.5 μ F cm⁻²) and over 5 times higher than laser-written porous carbon MSCs (<20 μ F cm⁻²). ⁵²

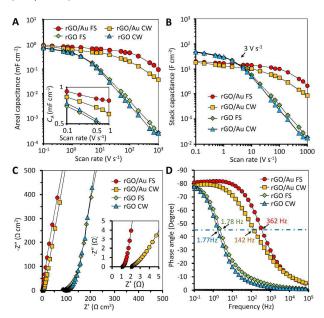


Fig. 3 Comparison of electrochemical performances of both the laser-written rGO/Au-MSCs and rGO-MSCs: A) areal capacitance C_A as a function of the scan rate (inset shows a magnified low-scan-rate region), B) stack capacitance C_S as a function of the scan rate, C) the Nyquist plot of the impedance of the MSCs (inset shows a magnified high-frequency region), and D) the Bode plot of impedance of the MSCs.

From volumetric perspective (Fig. 5B), the stacked capacitances of rGO/Au MSCs written by both FS laser and CW laser are remarkably higher than that of rGO MSCs without Au NPs at a scan rate from 3 V s $^{-1}$ to 1000 V s $^{-1}$, which is consistent with the areal

capacitance. For example, at 100 V s⁻¹, the stacked capacitance of rGO/Au FS-MSCs (10.2 F cm⁻³) is more than 30 times larger than those of the rGO based MSCs without Au NPs. At low scan rates below 3 V s⁻¹, the stacked capacitance of rGO MSCs without Au NPs (~50 F cm⁻³) is still remarkably higher than that of rGO/Au MSCs (~18 F cm⁻³), which is due to the thinner rGO microelectrodes without Au NPs than the rGO/Au microelectrodes. Nevertheless, the stacked capacitance of rGO/Au MSCs is still over 8 times larger than the previously reported laser-scripted MSCs (<2.5 F cm⁻³).

Note that the rGO/Au FS-MSC exhibits remarkably enhanced rate capabilities, for example, retaining 71% of its capacitance when the charging rate is increased from 0.1 V s $^{-1}$ to 10 V s $^{-1}$ and 50% for the increase from 0.1 V s $^{-1}$ to 100 V s $^{-1}$. These enhanced rate capabilities of the rGO/Au FS-MSC are attributed to the remarkably high specific capacitance at high scan rates.

Electrochemical impedance spectroscopy (EIS) provides a consistent insight for the superior performance of rGO/Au FS-MSCs as shown in the Nyquist plot of resistance (Z') vs capacitance (Z") (Fig. 5C). The high frequency region (the inset graph) shows small charge resistance for both the rGO/Au and rGO based MSCs and the steep Nyquist curves imply the short ion diffusion pathway and fast ion diffusion for such in-plane interdigitated geometry.⁴ The ESR, which is equivalent to the intersection point with the Z'-axis, is determined to be 1.1 Ω cm² for rGO/Au FS-MSCs and 2.1 Ω cm² for rGO/Au CW-MSCs. Note that these ESR values are on the order of 1% of those for the rGO based MSCs with no Au NPs-bridged rGO sheets, namely, 91.2 Ω cm² for rGO-FS and 103.6 Ω cm² for rGO-CW. Furthermore, the high characteristic frequency f = 362 Hz (corresponding time constant $\tau = 1/f = 2.76$ ms) at -45° phase angle⁴ for rGO/Au FS-MSCs (Fig. 5D) turns out to be significantly higher than those for rGO/Au CW-MSCs (142 Hz), rGO FS-MSCs (1.78 Hz) and rGO CW-MSCs (1.77 Hz). This high frequency satisfies the requirement of the ac line fliting (larger than 120 Hz).

In addition, the rGO/Au FS MSCs show features of large-area good mechanical flexibility (Supplementary Note 4, ESI) and an excellent cycle life (Fig. S4, ESI). The capacitance decays only a mere

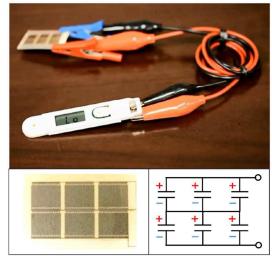


Fig. 4 A liquid crystal display (LCD) powered by an array of 6 rGO/Au FS-MSCs (the inset images show the actual rGO/Au FS-MSC array and its circuit diagram).

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1% from the initial specific capacitance after 10,000 repeated charge/discharge cycles at a scan rate of 50 V s⁻¹, and 19.7% from the initial specific capacitance at a scan rate of 1 V s⁻¹. As a demonstration, Fig. 6 shows that a liquid crystal display (LCD) is powered by a rGO/Au FS array of 6 MSCs (see Video S1).

Demonstration of three dimensional (3D) rGO/Au FS MSCs

3D designs based on micro- and nano-structured architectures could potentially boost the areal energy density by fully utilizing the limited space available for on chip energy storage. 68 To date, such architectures have been produced in planar and 3D devices by conventional lithography, 69 nozzle printing, 68 and colloidal templating methods, 70 respectively, whereas no work has been reported about the 3D MSCs fabricated by laser writing.

Here, proof-of-concept 3D rGO/Au FS MSCs are demonstrated in Fig. 7 using a layer-by-layer drop-casting/laser-writing process. It is well known that the laser power penetrating through the GO/HAuCl₄ film possesses an exponential decay along the depth⁷¹ owing to the absorption of the GO/HAuCl₄ gel layer. Additionally, the laser reduced rGO and Au NPs can also limit the laser penetration depth due to the strong surface plasmon resonance (SPR). 72, 73 As a result, the maximum thickness of surface reduced electrode is limited to about 500 nm because a thicker electrode would fall off from the substrate when immersed into DI water for washing. The weak bonding is caused by re-dispersion of unreacted GO sandwiched between the electrodes and paper substrate. However, if the deposition is controlled as the thickness of no more than 500 nm, a layer-by-layer assembly via repeating the dropcasting and laser reduction processes is practical to construct a 3D

electrode.

The photograph in Fig. 7A shows a laser-written 3D rGO/Au FS MSC, with a triangle shaped cross-sectional structure of microelectrodes (Fig. 7B). A typical SEM image in Fig. 7C clearly shows a multi-layer stacked cross-sectional structure of a 5-layer electrode with abundant micro-cavities between each layer. These cavities enlarge the interspace between the rGO/Au micromembranes to several micrometers. Nevertheless, few microcavities were observed for a single-layer microelectrode (Fig. 1B).

It is reasonable to expect that these micro-cavities are formed due to the release of gas during the reduction of GO and the coalescence of Au NPs, with an observation of multi-bubble generation (Fig. S5, ESI) with grayish smoke during laser writing. This diversity between a single-layer microelectrode and a multilayer microelectrode is probably due to the different paths of gas release during the laser writhing. Considering the fabrication of a 2layer microelectrode, for example, during writing of the first layer, the produced gas can escape directly from the GO/HAuCl₄ gel surface. In depositing the second layer, a significant amount of GO/HAuCl₄ gel may diffuse into the porous first-layer microelectrodes. During the laser writing with the increase of thickness, trapped gas can generate bubbles inside the first-layer microelectrodes, or between the first and second-layer microelectrodes. The bubbles grow and push the surrounding rGO/Au membranes and create micro-cavities, which significantly increase the layer thickness. This cavity-formation process is likely similar to that of the laser-fabricated micro-cavities found inside PMMA slides. 42 As a result, the thickness of a single-layer microelectrode is around 0.45 µm, whereas it suddenly increases to 2.5 µm for a 2-layer microelectrode. A nearly linear dependence of

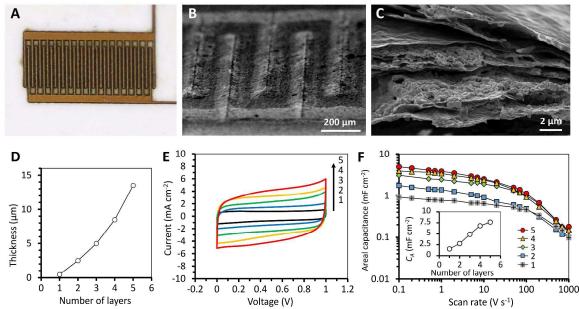


Fig. 5 3D rGO/Au-MSCs (Micro-supercapacitors) fabricated on a paper substrate: A) the optical image of a 5-layer 3D rGO/Au FS-MSC, B) the SEM image of the interdigitated 5-layer 3D rGO/Au microelectrodes, C) the cross-sectional view of a 5-layer 3D rGO/Au microelectrode, D) the maximum thickness of rGO/Au microelectrodes as a function of layer number, E) cyclic voltammetry (CV) curves obtained at a scan rate of 1 V s⁻¹ with an increasing number of layers (marked by the black arrow), and F) areal capacitance C_A as a function of the scan rate (inset shows areal capacitance C_A as a function of the number of layers).

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the maximum thickness on the layer number is observed for microelectrodes over 2 layers, reaching approximate 13.7 µm in the central thickness for a 5-layer microelectrode (Fig. 7D).

Meanwhile, the triangle shaped cross-sectional structure can be attributed to the Gaussian intensity profile of the focused laser beam, of which the light intensity at the central area is significantly higher than the surroundings. The larger micro-cavities and fused Au NPs are preferably formed at the central area due to a higher reduction, leading to a thicker rGO/Au membrane.

These 3D rGO/Au FS MSCs keep a quasi-rectangular shaped CV curves and linear increase of current density with an increasing number of layers as shown in Fig. 7E. This is consistent with the near-linear number of layers dependence of areal capacitance as shown in the inset of Fig. 7F.

Noteworthy, high rate capabilities are largely maintained (Fig. 7F and 7G) by comparing the 3D multi-layer MSCs to a 2D single-layer MSC. The 5-layer rGO F-MSC, for example, retaining 49% of its capacitance when the charging rate is increased from 0.1 V s⁻¹ to 10 V s⁻¹ and 23% for the increase from 0.1 V s⁻¹ to 100 V s⁻¹. Correspondingly, the specific capacitances are 4.92 mF cm⁻² at 0.1 V s⁻¹, 2.39 mF cm⁻² at 10 V s⁻¹, and 1.12 mF cm⁻² at 100 V s⁻¹, respectively. These values are comparable with those of previous reported high-rate MSCs (the best capacitance is 2.8 mF cm⁻² for rGO/CNT composite MSCs at a rate of 50 V s⁻¹), which yield promise for a more compact design of on-chip devices.

Conclusions

In summary, we successfully demonstrated flexible in-plane high performance rGO/Au MSCs that are fabricated through in-situ femtolaser writing. Without the need of complicated multi-step photolithography processes, the femtolaser writing allows for the simultaneous and direct reduction of GO/HAuCl₄ composites into a combination of rGO electrodes and Au collectors (Au NPs). It is evident that fused Au nanoparticle in-plane network significantly increases the conductivity meanwhile the porous graphene enhancing the capacitance. These flexible MSCs boast achievements of two order-of-magnitude-increased electrode conductivities of 1.1×10⁶ S m⁻¹ due to the highly conductive pathways created by Au NPs, with short ion diffusion pathways due to the in-plane design, superior rate capabilities (71% and 50% of capacitance retention for the charging rate increase from 0.1 V s⁻¹ to 10 V s⁻¹ and to 100 V s⁻¹, respectively), sufficiently high frequency responses (362 Hz, 2.76 ms time constant), large specific capacitance (0.77 mF/cm² at 1 V s⁻¹), and outstanding cycle stability (10,000 cycles). Moreover, proof-ofconcept 3D MSCs are demonstrated with enhanced areal capacitance (up to 4.92 mF cm⁻² at 1 V/s) while keeping high rate capabilities, which allows for the more compact on-chip design. Such high performance rGO/Au-FS MSCs promote their applications for flexible, portable and wearable electronic devices that require fast charge/discharge rates and high power densities. Furthermore, these new femtolaser-written MSCs can be potentially integrated with other electronic devices such as solar cells, gas sensors, fieldeffect transistors, and chip-level display devices.

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Notes and references

- J. Chmiola, C. Largeot, P.-L. Taberna, P. Simon and Y. Gogotsi, Science, 2010, 328, 480-483.
- Z. Niu, L. Zhang, L. Liu, B. Zhu, H. Dong and X. Chen, Adv Mater, 2013, 25, 4035-4042.
- M. F. El-Kady and R. B. Kaner, Nature communications, 2013, 4, 1475.
- Z. S. Wu, K. Parvez, X. Feng and K. Mullen, Nature communications, 2013, 4, 2487.
- D. Pech, M. Brunet, H. Durou, P. Huang, V. Mochalin, Y. Gogotsi, P. L. Taberna and P. Simon, Nat Nanotechnol, 2010, 5, 651-654.
- J. Lin, C. Zhang, Z. Yan, Y. Zhu, Z. Peng, R. H. Hauge, D. Natelson and J. M. Tour, Nano Lett, 2013, 13, 72-78.
- M. Beidaghi and C. Wang, Adv Funct Mater, 2012, 22, 4501-4510.
- M. Beidaghi and Y. Gogotsi, Energy & Environmental Science, 2014, 7, 867-884.
- G. Wang, H. Wang, X. Lu, Y. Ling, M. Yu, T. Zhai, Y. Tong and Y. Li, Adv Mater, 2014, 26, 2676-2682, 2615.
- W. Gao, N. Singh, L. Song, Z. Liu, A. L. Reddy, L. Ci, R. Vajtai, Q. Zhang, B. Wei and P. M. Ajayan, Nature nanotechnology, 2011, 6, 496-500.
- Y. Zhai, Y. Dou, D. Zhao, P. F. Fulvio, R. T. Mayes and S. Dai, Adv Mater, 2011, 23, 4828-4850.
- L. L. Zhang, X. Zhao, M. D. Stoller, Y. Zhu, H. Ji, S. Murali, Y. Wu, S. Perales, B. Clevenger and R. S. Ruoff, *Nano letters*, 2012, 12, 1806-1812.
- C. Zhang, W. Lv, Y. Tao and Q.-H. Yang, Energy & Environmental Science, 2015, 8, 1390-1403.
- J. J. Yoo, K. Balakrishnan, J. Huang, V. Meunier, B. G. Sumpter, A. Srivastava, M. Conway, A. L. Reddy, J. Yu, R. Vajtai and P. M. Ajayan, Nano Lett, 2011, 11, 1423-1427.
- M. F. El-Kady, V. Strong, S. Dubin and R. B. Kaner, *Science*, 2012, 335, 1326-1330.

46.

49.

57.

Energy & Environmental Science

- D. Tobjork and R. Osterbacka, Adv Mater, 2011, 23, 1935-1961.
- 17. R. Z. Li, A. Hu, T. Zhang and K. D. Oakes, *ACS applied materials & interfaces*, 2014, **6**, 21721-21729.
- A. Russo, B. Y. Ahn, J. J. Adams, E. B. Duoss, J. T. Bernhard and J. A. Lewis, *Advanced materials*, 2011, 23, 3426-3430.
- E. W. Nery and L. T. Kubota, Anal Bioanal Chem, 2013, 405, 7573-7595.
- Y. Wang, L. Ge, P. Wang, M. Yan, S. Ge, N. Li, J. Yu and J. Huang, Lab Chip, 2013, 13, 3945-3955.
- J. Wang, J. Jiu, M. Nogi, T. Sugahara, S. Nagao, H. Koga, P. He and K. Suganuma, Nanoscale, 2015, DOI: 10.1039/C4NR06494A.
- 22. D. D. Liana, B. Raguse, J. J. Gooding and E. Chow, ACS applied materials & interfaces, 2015.
- L. Ge, P. Wang, S. Ge, N. Li, J. Yu, M. Yan and J. Huang, *Anal Chem*, 2013, 85, 3961-3970.
- R. Fobel, A. E. Kirby, A. H. Ng, R. R. Farnood and A. R. Wheeler, *Adv Mater*, 2014, 26, 2838-2843.
- U. Zschieschang, T. Yamamoto, K. Takimiya, H. Kuwabara, M. Ikeda, T. Sekitani, T. Someya and H. Klauk, Advanced Materials, 2011, 23, 654-658.
- J. Huang, H. Zhu, Y. Chen, C. Preston, K. Rohrbach, J. Cumings and L. Hu, ACS Nano, 2013, 7, 2106-2113.
- Y. Fujisaki, H. Koga, Y. Nakajima, M. Nakata, H. Tsuji, T. Yamamoto, T. Kurita, M. Nogi and N. Shimidzu, Adv Funct Mater, 2014, 24, 1657-1663.
- L. Leonat, M. S. White, E. D. Głowacki, M. C. Scharber, T. Zillger, J. Rühling, A. Hübler and N. S. Sariciftci, *The Journal of Physical Chemistry C*, 2014, 118, 16813-16817.
- M. C. Barr, J. A. Rowehl, R. R. Lunt, J. Xu, A. Wang, C. M. Boyce, S. G. Im, V. Bulovic and K. K. Gleason, *Adv Mater*, 2011, 23, 3499-3505.
- D. H. Lien, Z. K. Kao, T. H. Huang, Y. C. Liao, S. C. Lee and J. H. He, ACS Nano, 2014, 8, 7613-7619.
- 31. L. Hu, H. Wu, F. La Mantia, Y. Yang and Y. Cui, *ACS Nano*, 2010, **4**, 5843-5848.
- 32. S. Leijonmarck, A. Cornell, G. Lindbergh and L. Wågberg, *Journal of Materials Chemistry A*, 2013, **1**, 4671-4677.
- L. Nyholm, G. Nystrom, A. Mihranyan and M. Stromme, *Adv Mater*, 2011, 23, 3751-3769.
- 34. G. Nyström, A. Razaq, M. Strømme, L. Nyholm and A. Mihranyan, *Nano letters*, 2009, **9**, 3635-3639.
- 35. L. Hu, H. Wu and Y. Cui, *Appl Phys Lett*, 2010, **96**, 183502.
- X. Zhang, Z. Lin, B. Chen, S. Sharma, C.-p. Wong, W. Zhang and Y. Deng, *Journal of Materials Chemistry A*, 2013, 1, 5835-5839.
- Z. B. Sun, X. Z. Dong, W. Q. Chen, S. Nakanishi, X. M. Duan and S. Kawata, *Advanced Materials*, 2008, 20, 914-919.
- 38. B. H. Cumpston, S. P. Ananthavel, S. Barlow, D. L. Dyer, J. E. Ehrlich, L. L. Erskine, A. A. Heikal, S. M. Kuebler, I.-Y. S. Lee and D. McCord-Maughon, *Nature*, 1999, **398**, 51-54.
- T. Tanaka, A. Ishikawa and S. Kawata, Appl Phys Lett, 2006, 88, 081107.
- 40. B.-B. Xu, L. Wang, Z.-C. Ma, R. Zhang, Q. Chen, C. Lv, B. Han, X.-Z. Xiao, X.-L. Zhang and Y.-L. Zhang, *ACS nano*, 2014.
- 41. Y. Y. Cao, N. Takeyasu, T. Tanaka, X. M. Duan and S. Kawata, *Small*, 2009, **5**, 1144-1148.
- C. Zheng, A. Hu, K. D. Kihm, Q. Ma, R. Li, T. Chen and W. Duley, Small, 2015, 11, 3007-3061.

 Y. Bellouard and M.-O. Hongler, Opt Express, 2011, 19, 6807-6821.

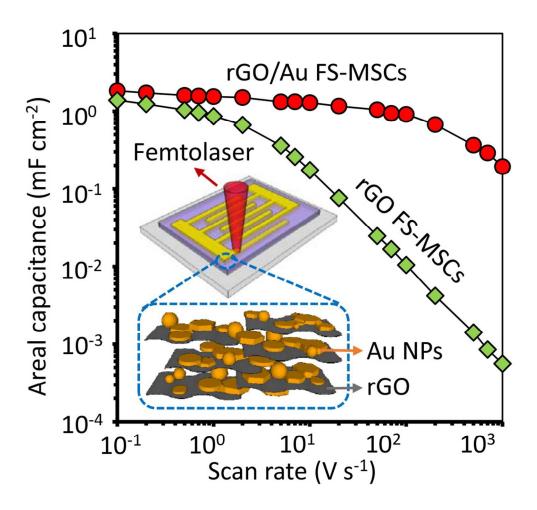
ARTICLE

- 44. Y. Zhang, L. Guo, S. Wei, Y. He, H. Xia, Q. Chen, H.-B. Sun and F.-S. Xiao, *Nano Today*, 2010, **5**, 15-20.
- P. Russo, A. Hu, G. Compagnini, W. W. Duley and N. Y. Zhou, *Nanoscale*, 2014, 6, 2381-2389.
 - S. Han, D. Wu, S. Li, F. Zhang and X. Feng, *Adv Mater*, 2014, **26**, 849-864.
 - S. Shukla, X. Vidal, E. P. Furlani, M. T. Swihart, K.-T. Kim, Y.-K. Yoon, A. Urbas and P. N. Prasad, Acs Nano, 2011, 5, 1947-1957.
 - S. Kawata, H.-B. Sun, T. Tanaka and K. Takada, *Nature*, 2001, **412**, 697-698.
 - B. B. Xu, H. Xia, L. G. Niu, Y. L. Zhang, K. Sun, Q. D. Chen, Y. Xu, Z. Q. Lv, Z. H. Li and H. Misawa, *Small*, 2010, **6**, 1762-1766.
- 50. L. Yuan, B. Yao, B. Hu, K. Huo, W. Chen and J. Zhou, *Energy & Environmental Science*, 2013, **6**, 470-476.
- H. Wang, J. T. Robinson, X. Li and H. Dai, J Am Chem Soc, 2009, 131, 9910-9911.
- J. B. In, B. Hsia, J.-H. Yoo, S. Hyun, C. Carraro, R. Maboudian and C. P. Grigoropoulos, Carbon, 2015, 83, 144-151.
- R.-Z. Li, A. Hu, D. Bridges, T. Zhang, K. D. Oakes, R. Peng,
 U. Tumuluri, Z. Wu and Z. Feng, *Nanoscale*, 2015, **7**, 7368-7377.
- 54. R. Pasricha, S. Gupta and A. K. Srivastava, *Small*, 2009, **5**, 2253-2259.
- 55. X. Zhou, X. Huang, X. Qi, S. Wu, C. Xue, F. Y. Boey, Q. Yan, P. Chen and H. Zhang, *The Journal of Physical Chemistry C*, 2009, **113**, 10842-10846.
- K. K. Kim, A. Reina, Y. Shi, H. Park, L.-J. Li, Y. H. Lee and J. Kong, *Nanotechnology*, 2010, 21, 285205.
 - S. M. Yoon, U. J. Kim, A. Benayad, I. H. Lee, H. Son, H. J. Shin, W. M. Choi, Y. H. Lee, Y. W. Jin, E. H. Lee, S. Y. Lee, J. Y. Choi and J. M. Kim, *ACS Nano*, 2011, **5**, 1353-1359.
- L. A. Porter, H. C. Choi, A. E. Ribbe and J. M. Buriak, *Nano Letters*, 2002, 2, 1067-1071.
- J. Ou, C. Chang, Y. Sung, K. Ou, C. Tseng, H. Ling and M. Ger, Colloids and Surfaces A: Physicochemical and Engineering Aspects, 2007, 305, 36-41.
- B. S. Kong, J. Geng and H. T. Jung, Chem Commun (Camb), 2009, DOI: 10.1039/b821920f, 2174-2176.
- M. S. Abdou and S. Holdcroft, Synthetic Met, 1993, 60, 93-96.
- 62. B. Raton, *Journal*, 2003.
- H. C. Choi, M. Shim, S. Bangsaruntip and H. Dai, J Am Chem Soc, 2002, 124, 9058-9059.
- S. M. Kim, K. K. Kim, Y. W. Jo, M. H. Park, S. J. Chae, D. L. Duong, C. W. Yang, J. Kong and Y. H. Lee, *Acs Nano*, 2011, 5, 1236-1242.
- A. Benayad, H.-J. Shin, H. K. Park, S.-M. Yoon, K. K. Kim, M. H. Jin, H.-K. Jeong, J. C. Lee, J.-Y. Choi and Y. H. Lee, *Chem Phys Lett*, 2009, 475, 91-95.
- W. Si, C. Yan, Y. Chen, S. Oswald, L. Han and O. G. Schmidt, Energy & Environmental Science, 2013, 6, 3218-3223.
- W.-W. Liu, Y.-Q. Feng, X.-B. Yan, J.-T. Chen and Q.-J. Xue, *Adv Funct Mater*, 2013, 23, 4111-4122.
 - K. Sun, T. S. Wei, B. Y. Ahn, J. Y. Seo, S. J. Dillon and J. A. Lewis, Advanced Materials, 2013, 25, 4539-4543.

Energy & Environmental Science

- S. R. Gowda, A. Leela Mohana Reddy, X. Zhan and P. M. Ajayan, *Nano Lett*, 2011, 11, 3329-3333.
- 70. H. Zhang, X. Yu and P. V. Braun, *Nat Nanotechnol*, 2011, **6**, 277-281.
- 71. Y. Zhou, Q. Bao, B. Varghese, L. A. Tang, C. K. Tan, C. H. Sow and K. P. Loh, *Adv Mater*, 2010, **22**, 67-71.
- D. K. Lim, A. Barhoumi, R. G. Wylie, G. Reznor, R. S. Langer and D. S. Kohane, *Nano Lett*, 2013, 13, 4075-4079.
- 73. A. F. Zedan, S. Moussa, J. Terner, G. Atkinson and M. S. El-Shall, *ACS nano*, 2012, **7**, 627-636.

On-chip energy devices and integrated manufacturing are urgently demanded for portable electronics and modern information societies. It has been a challenge to fabricate a miniaturized energy storage device on flexible substrates for current battery technology. In this work, we have invented a direct laser writing method to develop an electric double-layered supercapacitor providing high energy storage performance. This laser writing method allows innovative fabrication of a highly conductive- and large capacitive electrode by photonic reductions of both Au nanoparticles and graphene simultaneously from a HAuCl₄ and graphene oxide slurry using a femtosecond fiber laser. Interconnected gold nanoparticles embedded in porous graphene composite provide low-loss electrical paths and effective channels for fast ion diffusion. Using an extrusion technique, we can also transform this in-plane microsupercapacitor into a three-dimensional architecture, which further increases the areal energy densities. Furthermore, our paper-based fabrication provides all-paper-based systems for environment-friendly flexible electronics. This work is also promising to stimulate further works for high efficiency on-chip energy devices for wearable electronics.



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